

## IN THE CLAIMS

Please amend the claims to read as follows:

### Listing of Claims

1. (Currently Amended) A battery mounted integrated circuit device, comprising:

(1) a semiconductor substrate;

(2) a solid state battery mounted on said semiconductor substrate;

(3) an integrated circuit mounted on said semiconductor substrate;

(4) a first diffusion layer, containing an N-type impurity, formed between a region of said semiconductor substrate where said solid state battery is mounted and a region of said semiconductor substrate where said integrated circuit is mounted; and

(5) a second diffusion layer, containing an N-type impurity, formed below said region of said semiconductor substrate where said solid state battery is mounted, and overlapping with said first diffusion layer, wherein:

said solid state battery comprises a positive electrode, a negative electrode, and a solid electrolyte disposed between said positive electrode and said negative electrode,

the concentration of said N-type impurity in said first diffusion layer is higher than the concentration of said N-type impurity in said second diffusion layer, and

at least when said solid state battery is being charged and discharged, said first diffusion layer and said second diffusion layer have a positive potential not less than the potential of the positive electrode with respect to the negative electrode,

said solid state battery is carried on the second diffusion layer, and

said first diffusion layer surrounds said region where said solid state battery is mounted.

2. (Original) The battery mounted integrated circuit device in accordance with claim 1, wherein the concentration of said N-type impurity in said first diffusion layer is not less than  $1 \times 10^{19}$  atoms/cm<sup>3</sup>.

3. (Previously Presented) The battery mounted integrated circuit device in accordance with claim 1, wherein the ratio of the concentration of said N-type impurity in said first diffusion layer to the concentration of said N-type impurity in said second diffusion layer is not less than  $1 \times 10^1$  and not more than  $1 \times 10^5$ .

4-6. (Canceled) .

7. (Original) The battery mounted integrated circuit device in accordance with claim 1, further comprising a wiring layer for connecting said first diffusion layer with the outside.

8. (Original) The battery mounted integrated circuit device in accordance with claim 1, further comprising a potential controlling section for controlling a potential to be applied to said first diffusion layer and said second diffusion layer.